





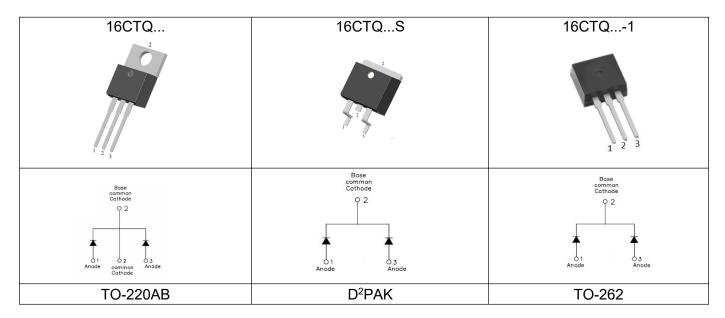
16CTQ.../16CTQ...S /16CTQ...-1 SCHOTTKY RECTIFIER

Features

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: 100% Pure Tin
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection



Maximum Ratings:

Characteristics	Symbol	Condition		Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V _{RRM}	-	80	16CTQ080 16CTQ080S 16CTQ080-1	V
DC Blocking Voltage	$egin{array}{c} V_{RWM} \ V_{R} \end{array}$		100	16CTQ100 16CTQ100S 16CTQ100-1	
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=105°C, rectangular wave form		8(Per Leg) 16(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse 280		А	

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (Per Leg)*	V _{F1}	@ 8A, Pulse, T _J = 25 °C @ 16A, Pulse, T _J = 25 °C	0.71 0.78	0.75 0.88	V
	V _{F2}	@ 8A, Pulse, T_J = 125 °C@ 16A, Pulse, T_J = 125 °C	0.55 0.63	0.58 0.69	V
Reverse Current (Per Leg)*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	0.0003	0.55	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	0.2	7.0	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C$ $f_{SIG} = 1MHz$	400	500	pF
Typical Series Inductance (per leg)	Ls	L _S Measured lead to lead 5 mm from package body		-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

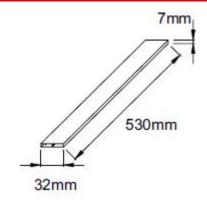
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	Τ _J	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R _{θJC}	DC operation	3.25	°C/W
Typical Thermal Resistance, Case to Heat Sink	$R_{ heta JL}$	DC operation	0.50	°C/W
Case Style	TO-220AB D ² PAK TO-262			

Tube Specification

Device	Package	Weight	Shipping
16CTQ	TO-220AB	1.8g	50pcs / tube
16CTQS	D ² PAK	1.85g	800pcs / reel
16CTQ1	TO-262	1.85g	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification(TO-220AB/TO-262)



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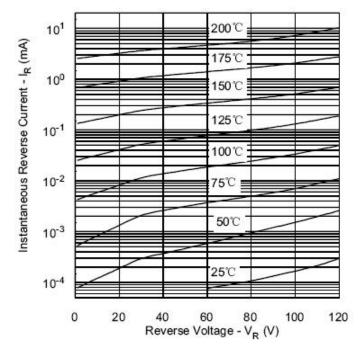


Ratings and Characteristics Curves

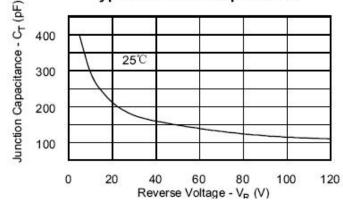
Typical Forward Characteristics

10¹ 200°C 175°C Instantaneous Forward Current - I F (A) 10⁰ 125℃ 25°C 10-1 10-2 0.1 0.2 0.3 0.4 0.5 0.6 0.7 0.8 Forward Voltage Drop - V_F(V)

Typical Reverse Characteristics



Typical Junction Capacitance



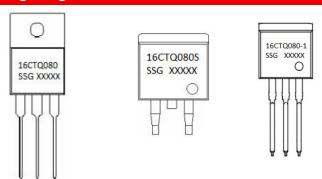
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Marking Diagram



Where XXXXX is YYWWL

= Forward Current (16A) 16 C TQ = Configuration

= Device Type

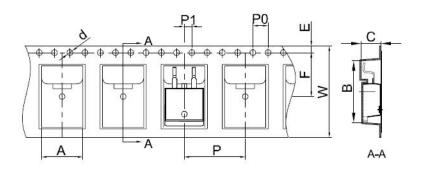
80/100 = Reverse Voltage (80V/100V) S/-1 = Package type

SSG = SSG = Year $\mathsf{W}\mathsf{W}$ = Week = Lot Number

Cautions: Molding resin

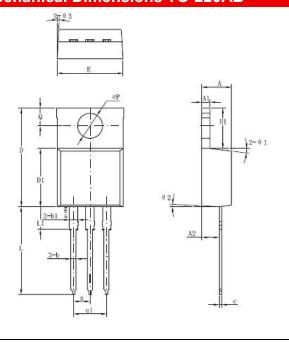
Epoxy resin UL:94V-0

Carrier Tape Specification D²PAK



Symbol	Millimeters		
	Min.	Max.	
Α	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

Mechanical Dimensions TO-220AB



Symbol	Dimensions in millimeters		
	Min	Typical	Max
Α	3.56	-	4.83
A1	0.51	-	1.40
A2	2.03	-	2.92
b	0.38	-	1.02
b1	1.14	-	1.78
С	0.31	-	0.61
D	14.22	-	16.51
D1	8.38	-	9.42
E	9.65	-	10.67
е	-	2.54	-
e1	-	5.08	-
H1	5.84	-	6.86
L	12.70	-	14.73
L1	-	-	6.35
ФР	-	3.56	-
Q	2.54	-	3.43

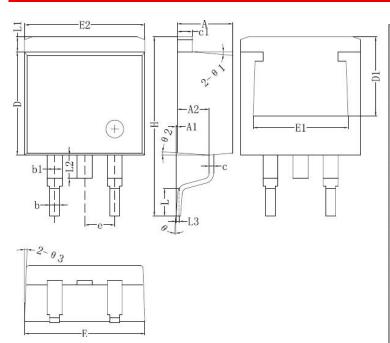
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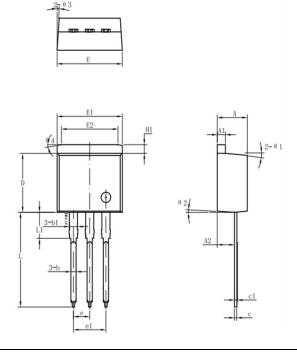


Mechanical Dimensions D²PAK



Symbol	Dimensions in millimeters		
	Min.	Max.	
Α	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
С	0.31	0.74	
c1	1.14	1.65	
D	8.38	8.65	
D1	6.86		
E1	6.22		
E2	9.65	10.67	
е	2.54BSC		
Н	14.60	15.88	
L	1.78	2.80	
L1	-	1.68	
L2	- 1.78		
L3	0.255BSC		
Θ	0	8°	

Mechanical Dimensions TO-262



Crosshad	Millimeters			
Symbol	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A 1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.55	8.70	8.85	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.18	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.70	
L1	1.17	1.27	1.40	
L2			2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		4°		
e3		4°		

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